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MOSFET - Power, DUAL COOL[®] N-Channel, DFN8 5x6 60 V, 1.5 mΩ, 235 A NTMFSC1D6N06CL

Features

- Advanced Dual-sided Cooled Packaging
- Ulra Low R_{DS(on)}
- MSL1 Robust Packaging Design

Typical Applications

- Orring FET/Load Switching
- Synchronous Rectifier
- DC-DC Conversion

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Parameter		Symbol	Value	Unit	
Drain-to-Source Voltag	-to-Source Voltage		V _{DSS}	60	V
Gate-to-Source Voltage	Э		V _{GS}	±20	V
Continuous Drain Current $R_{\theta JC}$ (Note 2)	Steady State			235	A
Power Dissipation $R_{\theta JC}$ (Note 2)			PD	166	W
Continuous Drain Current R _{θJA} (Notes 1, 2)	Steady State	T _A = 25°C	Ι _D	36	A
Power Dissipation $R_{\theta JA}$ (Notes 1, 2)			PD	3.8	W
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	900	А
Operating Junction and Range	Storage T	emperature	T _J , T _{stg}	–55 to +175	°C
Source Current (Body D	Image TemperatureT_J, T_{stg}-55 to +175dy Diode)Is164	А			
Single Pulse Drain-to-Source Avalanche Energy ($I_{L(pk)} = 17 A$)		E _{AS}	451	mJ	
Lead Temperature Soldering Reflow for Solder- ing Purposes (1/8" from case for 10 s)		ΤL	300	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 2)	$R_{\theta JC}$	0.9	°C/W
Junction-to-Top Source - Steady State (Note 2)	$R_{\theta JC}$	1.4	
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	39	

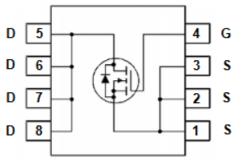
1. Surface-mounted on FR4 board using a 1 in² pad size, 1 oz Cu pad.

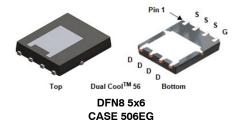
2. The entire application environment impacts the thermal resistance values shown,

they are not constants and are only valid for the particular conditions noted.

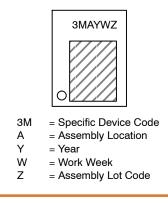
V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
60 V	1.5 mΩ @ 10 V	235 A
00 V	$2.3~\mathrm{m}\Omega$ @ $4.5~\mathrm{V}$	200 A

N-Channel MOSFET





MARKING DIAGRAM



ORDERING INFORMATION

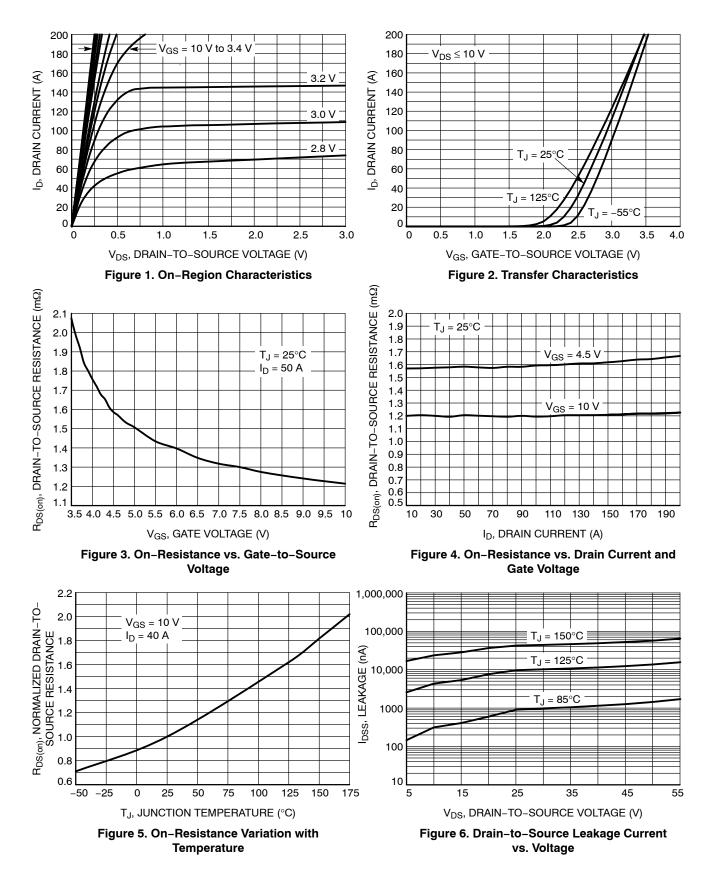
See detailed ordering and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

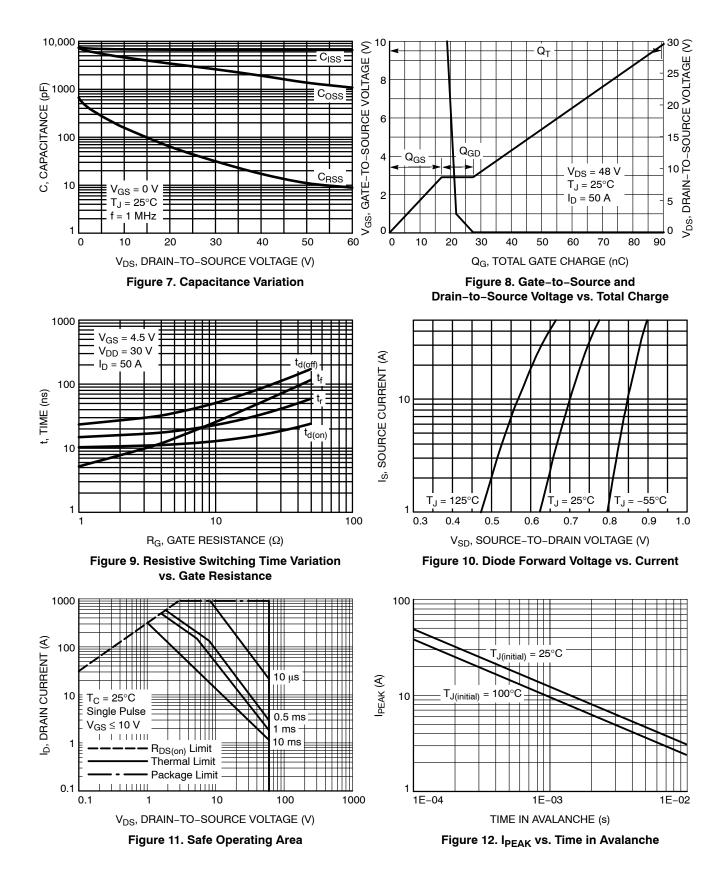
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit	
OFF CHARACTERISTICS								
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 250 μA		60			V	
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J	$I_D = 250 \ \mu A$, ref to $25^{\circ}C$			12.7		mV/°C	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 60 V	T _J = 25°C T _J = 125°C			10 100	μΑ	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS}	= 20 V			100	nA	
ON CHARACTERISTICS (Note 3)								
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} = V _{DS} , I _D =	= 250 μA	1.2		2.0	V	
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J	I _D = 250 μA, ref	to 25°C		-5.8		mV/°C	
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 50 A		1.25	1.5	mΩ	
		V _{GS} = 4.5 V	I _D = 50 A		1.65	2.3		
Gate-Resistance	R _G	T _A = 25°	С		2		Ω	
CHARGES & CAPACITANCES						-		
Input Capacitance	C _{ISS}	V_{GS} = 0 V, f = 1 MHz, V_{DS} = 25 V			6660		pF	
Output Capacitance	C _{OSS}				3000			
Reverse Transfer Capacitance	C _{RSS}				45			
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 4.5 V, V_{DS} = 30 V, I_{D} = 50 A			41		nC	
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 10 V, V_{DS} = 30 V, I_{D} = 50 A			91			
Gate-to-Source Charge	Q _{GS}				17			
Gate-to-Drain Charge	Q _{GD}				9			
Plateau Voltage	V _{GP}				2.9		V	
SWITCHING CHARACTERISTICS (Note 3)								
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 10 V, V_{DS} = 48 V, I_{D} = 50 A, R_{G} = 1 Ω			14.5		ns	
Rise Time	t _r				55.6			
Turn-Off Delay Time	t _{d(OFF)}				47.5			
Fall Time	t _f				14.1			
DRAIN-SOURCE DIODE CHARACTERISTICS	3							
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$	$T_J = 25^{\circ}C$		0.78	1.2	2 V	
		I _S = 50 A	T _J = 125°C		0.66		-	
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _S /dt = 100 A/μs,			76		ns	
Reverse Recovery Charge	Q _{RR}	I _S = 50 A	N N		130		nC	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.3. Switching characteristics are independent of operating junction temperatures.

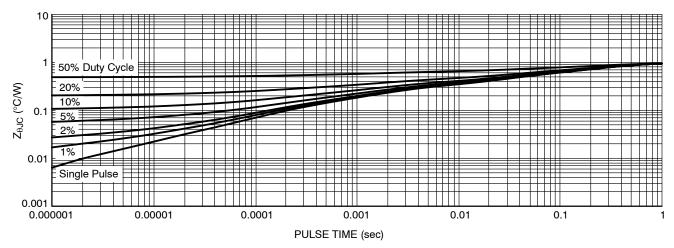
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS





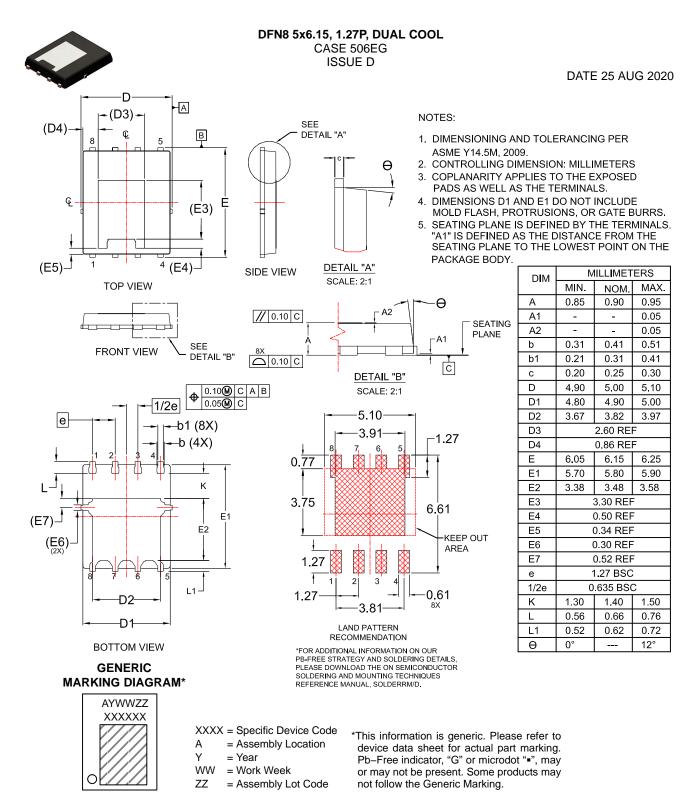
ORDERING INFORMATION

Device	Device Marking	Package	Shipping [†]
NTMFSC1D6N06CL	612LDC	DFN8 5x6 (Pb–Free/Halogen Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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